TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT Process)

2SC3620

Color TV Horizontal Driver Applications Color TV Chroma Output Applications

- High breakdown voltage: VCEO = 300 V
- Recommended for chroma output and driver applications for line-operated TV horizontal.

Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	300	V
Collector-emitter voltage	V _{CEO}	300	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	IC	100	mA
Base current	Ι _Β	50	mA
Collector power dissipation (Ta = 25°C)	P _C	1.5	W
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

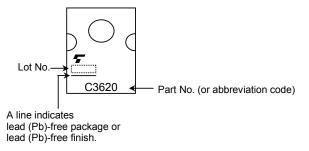
1. EMITTER 2. COLLECTOR 3. BASE JEDEC JEITA TOSHIBA 8.3MAX. 93.1±0.1 2.3±

Weight: 0.82 g (typ.)

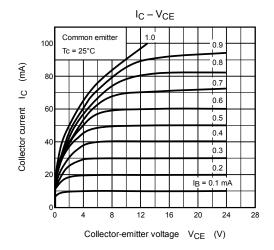
Electrical Characteristics (Tc = 25°C)

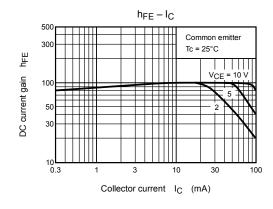
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 240 V, I _E = 0	_	_	1.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 7 V, I _C = 0		_	1.0	μA
DC current gain	h _{FE (1)}	V _{CE} = 10 V, I _C = 50 mA	40	_	170	
	h _{FE (2)}	V _{CE} = 10 V, I _C = 100 mA	20	_	1	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 100 mA, I _B = 20 mA	_	_	1.0	V
Base-emitter saturation voltage	V _{BE (sat)}	I _C = 100 mA, I _B = 20 mA	_	_	1.2	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 30 mA	50	_	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 50 V, I _E = 0, f = 1 MHz	_	_	5.0	pF

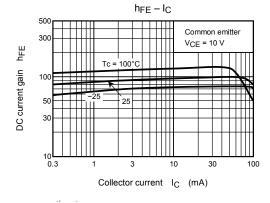
Marking

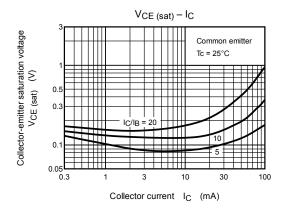


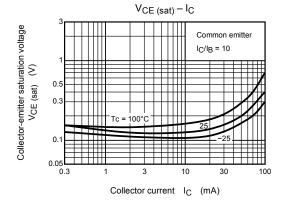
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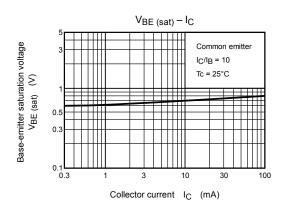


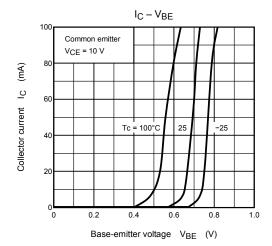


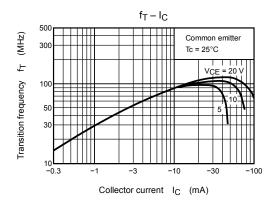


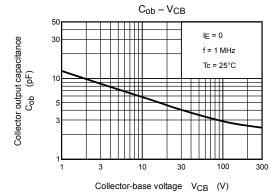


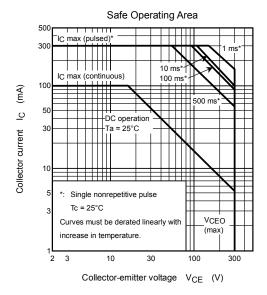












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